

DESCRIPTION

PLCC-2 package.

### VSMF970011X01

AUTOMOTIVE

COMPLIANT

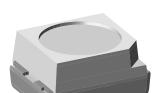
HALOGEN

FREE GREEN

(5-2008)

Vishay Semiconductors

# High Speed Infrared Emitting Diode, 890 nm



VSMF970011X01 is a high speed infrared emitting diode in

GaAlAs double hetero (DH) technology in a miniature

948553

#### **FEATURES**

Package type: surface-mount

• Package form: PLCC-2

• Dimensions (L x W x H in mm): 3.5 x 2.8 x 1.75

Peak wavelength: λ<sub>p</sub> = 890 nm

High reliability

· High radiant power

· High radiant intensity

• Angle of half sensitivity:  $\varphi = \pm 60^{\circ}$ 

· Low forward voltage

· Suitable for high pulse current operation

• Floor life: 168 h, MSL 3, according to J-STD-020

• Lead (Pb)-free reflow soldering

AEC-Q101 qualified

 Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>



- Automotive sensors
- Rain sensor
- Infrared high speed remote control and free air data transmission systems

| PRODUCT SUMMARY |                        |              |                             |                     |
|-----------------|------------------------|--------------|-----------------------------|---------------------|
| COMPONENT       | I <sub>e</sub> (mW/sr) | φ <b>(°)</b> | $\lambda_{\mathbf{p}}$ (nm) | t <sub>r</sub> (ns) |
| VSMF970011X01   | 9                      | ± 60         | 890                         | 50                  |

#### Note

• Test condition see table "Basic Characteristics"

| ORDERING INFORMATION |               |                              |              |  |  |
|----------------------|---------------|------------------------------|--------------|--|--|
| ORDERING CODE        | PACKAGING     | REMARKS                      | PACKAGE FORM |  |  |
| VSMF970011X01-GS08   | Tape and reel | MOQ: 7500 pcs, 1500 pcs/reel | PLCC-2       |  |  |
| VSMF970011X01-GS18   | Tape and reel | MOQ: 8000 pcs, 8000 pcs/reel | PLCC-2       |  |  |

#### Note

· MOQ: minimum order quantity

| <b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |                                |                   |             |      |  |
|--|--------------------------------|-------------------|-------------|------|--|
| PARAMETER  | TEST CONDITION                 | SYMBOL            | VALUE       | UNIT |  |
| Reverse voltage  |                                | $V_R$             | 5           | V    |  |
| Forward current  |                                | I <sub>F</sub>    | 100         | mA   |  |
| Surge forward current  | t <sub>p</sub> = 100 μs        | I <sub>FSM</sub>  | 200         | mA   |  |
| Power dissipation  |                                | P <sub>V</sub>    | 170         | mW   |  |
| Junction temperature   |                                | Tj                | 110         | °C   |  |
| Operating temperature range  |                                | T <sub>amb</sub>  | -40 to +105 | °C   |  |
| Storage temperature range  |                                | T <sub>stg</sub>  | -40 to +110 | °C   |  |
| Soldering temperature  | According to Fig. 8, J-STD-020 | T <sub>sd</sub>   | 260         | °C   |  |
| Thermal resistance junction-to-ambient   |                                | R <sub>thJA</sub> | 250         | K/W  |  |





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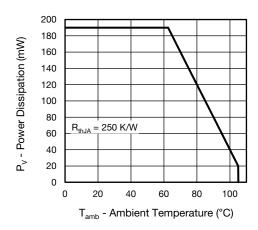


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

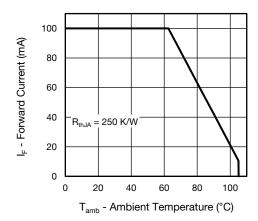


Fig. 2 - Forward Current Limit vs. Ambient Temperature

| BASIC CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified) |   |                       |      |       |      |       |
|--|---|-----------------------|------|-------|------|-------|
| PARAMETER  | TEST CONDITION                                  | SYMBOL                | MIN. | TYP.  | MAX. | UNIT  |
| Forward voltage  | $I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$     | V <sub>F</sub>        | -    | 1.6   | 1.9  | V     |
|  | $I_F = 200 \text{ mA}, t_p = 100 \mu \text{s}$  | V <sub>F</sub>        | -    | 1.9   | 2.5  | V     |
| Temperature coefficient of V <sub>F</sub>                                    | I <sub>F</sub> = 100 mA                         | TK <sub>VF</sub>      | -    | -1.1  | -    | mV/K  |
| Reverse current  | V <sub>R</sub> = 5 V                            | I <sub>R</sub>        | -    | -     | 10   | μΑ    |
| Junction capacitance   | $V_R = 0 \text{ V, } f = 1 \text{ MHz, } E = 0$ | Cj                    | -    | 160   | -    | pF    |
| Radiant intensity  | $I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$     | l <sub>e</sub>        | 5    | 9     | -    | mW/sr |
| Radiant power  | $I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$     | фe                    | -    | 30    | -    | mW    |
| Temperature coefficient of φ <sub>e</sub>                                    | I <sub>F</sub> = 100 mA                         | TKφ <sub>e</sub>      | -    | -0.46 | -    | %/K   |
| Angle of half intensity  |   | φ                     | -    | ± 60  | -    | 0     |
| Peak wavelength  | I <sub>F</sub> = 100 mA                         | λρ                    | -    | 890   | -    | nm    |
| Spectral bandwidth   | I <sub>F</sub> = 100 mA                         | $\Delta\lambda_{1/2}$ | -    | 40    | -    | nm    |
| Temperature coefficient of $\lambda_p$                                       | I <sub>F</sub> = 100 mA                         | TKλ <sub>p</sub>      | -    | 0.33  | -    | nm/K  |
| Rise time  | I <sub>F</sub> = 100 mA                         | t <sub>r</sub>        | -    | 50    | -    | ns    |
| Fall time  | I <sub>F</sub> = 100 mA                         | t <sub>f</sub>        | -    | 50    | -    | ns    |

### **BASIC CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

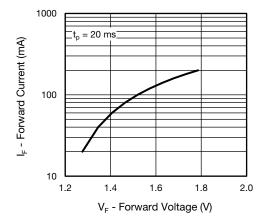


Fig. 3 - Forward Current vs. Forward Voltage

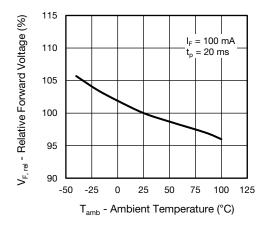


Fig. 4 - Relative Forward Voltage vs. Ambient Temperature





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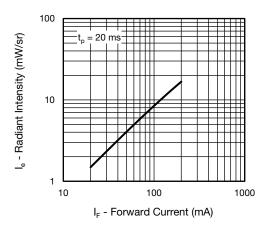


Fig. 5 - Radiant Intensity vs. Forward Current

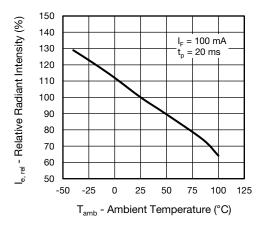


Fig. 6 - Relative Radiant Intensity vs. Ambient Temperature

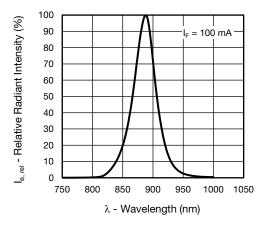


Fig. 7 - Relative Radiant Intensity vs. Wavelength

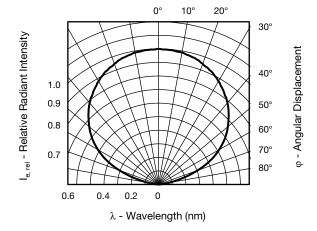
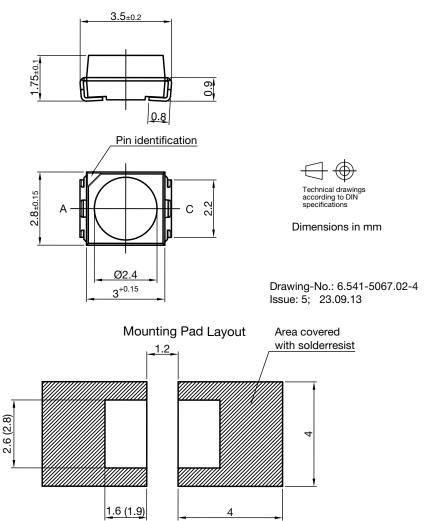


Fig. 8 - Relative Radiant Intensity vs. Angular Displacement



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#### **PACKAGE DIMENSIONS** in millimeters



Dimensions: Reflow and vapor phase (wave soldering)

#### **REFLOW SOLDER PROFILE**

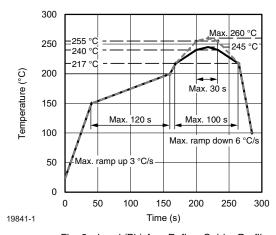


Fig. 9 - Lead (Pb)-free Reflow Solder Profile according to J-STD-020

#### **DRYPACK**

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

#### **FLOOR LIFE**

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label:

Floor life: 168 h

Conditions: T<sub>amb</sub> < 30 °C, RH < 60 %

Moisture sensitivity level 3, according to J-STD-020.

#### **DRYING**

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40  $^{\circ}$ C (+ 5  $^{\circ}$ C), RH < 5  $^{\circ}$ M.

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#### TAPE AND REEL

PLCC-2 components are packed in antistatic blister tape (DIN IEC (CO) 564) for automatic component insertion. Cavities of blister tape are covered with adhesive tape.

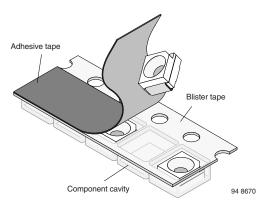


Fig. 10 - Blister Tape

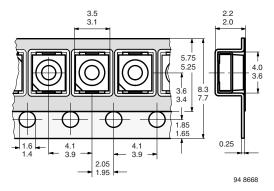


Fig. 11 - Tape Dimensions in mm for PLCC-2

#### **MISSING DEVICES**

A maximum of 0.5 % of the total number of components per reel may be missing, exclusively missing components at the beginning and at the end of the reel. A maximum of three consecutive components may be missing, provided this gap is followed by six consecutive components.

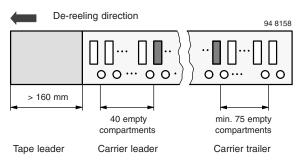


Fig. 12 - Beginning and End of Reel

The tape leader is at least 160 mm and is followed by a carrier tape leader with at least 40 empty compartements. The tape leader may include the carrier tape as long as the cover tape is not connected to the carrier tape. The least component is followed by a carrier tape trailer with a least 75 empty compartements and sealed with cover tape.

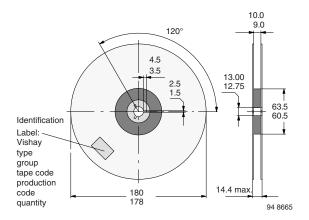


Fig. 13 - Dimensions of Reel-GS08

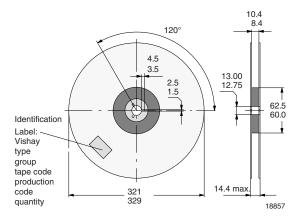


Fig. 14 - Dimensions of Reel-GS18

### **COVER TAPE REMOVAL FORCE**

The removal force lies between 0.1 N and 1.0 N at a removal speed of 5 mm/s. In order to prevent components from popping out of the blisters, the cover tape must be pulled off at an angle of 180° with regard to the feed direction.

## End of Life July-2021 - Alternative Device: VSMY3890X01



# VSMF970011X01

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